2.4~2.5 GHz Power Amplifier

### 2008. 08. 29 Update

#### DESCRIPTION

**AP1110** is a linear, low current power amplifier in ISM band utilizing InGaP /GaAs HBT process. The AP1110 is well suitable to be used for portable, low current 2.4GHz WLAN applications as well as for BT (Bluetooth) Class1 applications.

AP1110 is packaged in **2x2** compact profile. For WLAN application, it features low current of **85mA** at linear power of **18.5dBm**, gain of 26dB under 3.3V. For Bluetooth applications, it features of gain at 26 dB; typical power of **23dBm** and PAE of **40%** under 3.3V. AP1110 is also suitable for the new BT 2.0 (EDR) standard.

### **Major Applications**

- Bluetooth Class 1 including V1.1,1.2
  & (2.0)EDR standard
- IEEE 802.11b/g WLAN system
- WLAN Portable Devices
- WLAN USB Devices
- Other 2.4 GHz ISM Band

### KEY FEATURES

Ultra Small Profile: 2x2(mm), DFN-8pin

# **WLAN Applications:**

(Under Vc=3.3V, Vref=2.8V)

- LOW Current: 85mA at 18.5dBm
- High efficiency: PAE: 25% at 18dBm
- Gain: 26 dB

# **BT Applications:**

(BT V.1.1&1.2, Under Vc=3.3V, Vref=2.85V)

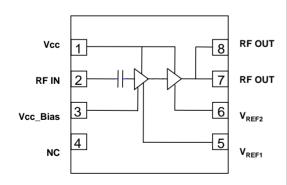
- LOW Current: 85mA at 18dBm 60mA at 16dBm 50mA at 14dBm
- High efficiency: PAE: 40% at 23dBm
- Gain: 26 dB
- Harmonic: -33dBc at 23dBm

#### (BT EDR version, under Vc&Vref=3.3V)

- LOW Current: 110mA at 18dBm 95mA at 16dBm 75mA at 14dBm
- Gain: 23dB

Note: The different applications are based on different outside circuit, please refer to the Application Note for more details.

### **Functional Block Diagram**



DFN - 8 pin, 2 x 2 (mm)

#### **Pin Details**

| T III Details   |                   |  |  |  |  |
|-----------------|-------------------|--|--|--|--|
| Pin<br>Number   | Name              | Description  |  |  |  |
| 1               | Vcc               | Supply voltage.  |  |  |  |
| 2               | RF IN             | RF input.  |  |  |  |
| 3               | Vcc_Bias          | Supply voltage for bias circuit.   |  |  |  |
| 4               | NC                | No connection.   |  |  |  |
| 5               | V <sub>REF1</sub> | PA 1 <sup>st</sup> stage bias control voltage.   |  |  |  |
| 6               | V <sub>REF2</sub> | PA 2 <sup>nd</sup> stage bias control voltage.   |  |  |  |
| 7               | RF OUT            | RF output. Require external  |  |  |  |
| 8               | RF OUT            | matching.  |  |  |  |
| Package<br>Base | Center Metal      | The package ground provides circuit ground as well as heat dissipation path for the power amplifier. |  |  |  |

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### **Electrical Characteristics: WLAN Applications**

Under Vc=3.3V, Vref=2.8V, Ta=25°C

| PARAMETERS                      | CONDITION    | SYMBOL | MIN. | TYP. | MAX. | UNIT |
|---------------------------------|--------------|--------|------|------|------|------|
| Freq.                           |              | f      | 2.4  |      | 2.5  | GHz  |
| Total current                   | Pout=18.5dBm | Icc    |      | 85   |      | mA   |
| Basic control reference current | Icq=21mA     | Iref   |      | 0.5  |      | mA   |
| Power Gain                      | Pout=18dBm   | Gp     |      | 26.5 |      | dB   |
| Quiescent current               |              | Icq    |      | 21   |      | mA   |
| Input VSWR                      |              |        |      | 1.5  |      |      |
| Output VSWR                     |              |        |      | 2    |      |      |
| Output power                    | EVM 3%       | Pout   |      | 18.5 |      | dBm  |
| PAE                             |              | PAE    |      | 25   |      | %    |

Note: For high power application, Vcc = Vbias = 4.5 V is what we recommend and please make an advance contact with RFIC.

### **Absolute Maximum Ratings**

| <u>Parameter</u>                 | Rating         | <u>Unit</u> |  |
|----------------------------------|----------------|-------------|--|
| DC Power Supply For<br>Collector | +5             | V           |  |
| DC Supply Current For Collector  | 280            | mA          |  |
| RF Input Power                   | +5             | dBm         |  |
| Operating Ambient<br>Temperature | -40 to +85     | °C          |  |
| Storage Temperature              | -40 to<br>+125 | °C          |  |

#### **Important Note:**

The information provided in this datasheet is deemed to be accurate and reliable only at present time. RFIC Technology Corp. reserves the right to make any changes to the specifications in this datasheet without prior notice.



Caution: ESD Sensitive

Appropriate precaution in handling, packaging And testing devices must be observed.

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### **Electrical Characteristics: BT Applications**

BT V.1.0-1.2, under Vc=3.3V, Vref=2.85V, Ta=25°C

| PARAMETERS                      | CONDITION  | SYMBOL | MIN. | TYP. | MAX. | UNIT |
|---------------------------------|------------|--------|------|------|------|------|
| Freq.                           |            | f      | 2.4  |      | 2.5  | GHz  |
| Total current                   | Pout=23dBm |        |      | 140  |      |      |
|                                 | Pout=20dBm | Icc    |      | 95   |      | mA   |
|                                 | Pout=14dBm |        |      | 50   |      |      |
| Basic control reference current | Icq=18mA   | Iref   |      | 0.5  |      | mA   |
| Power Gain                      | Pout=20dBm | Gp     |      | 26   |      | dB   |
| Quiescent current               |            | Icq    |      | 18   |      | mA   |
| Harmonic                        | Pout=23dBm | 2f     |      | -33  |      | dBc  |
| Input VSWR                      |            |        |      | 2    |      |      |
| Output VSWR                     |            |        |      | 2.5  |      |      |
| PAE                             | Pout=23dBm | PAE    |      | 40   |      | %    |
| Power                           |            | P1dB   |      | 23   |      | dBm  |

### BT v.2.0 (EDR), under Vc&Vref=3.3V, Ta=25°C

| PARAMETERS    | CONDITION  | SYMBOL | MIN. | TYP. | MAX. | UNIT |
|---------------|------------|--------|------|------|------|------|
| Freq.         |            | f      | 2.4  |      | 2.5  | GHz  |
| Total current | Pout=18dBm |        |      | 110  |      |      |
|               | Pout=16dBm | Icc    |      | 95   |      | mA   |
|               | Pout=14dBm |        |      | 75   |      |      |
| Power Gain    | Pout=18dBm | Gp     |      | 23   |      | dB   |
| Harmonic      | Pout=18dBm | 2f     |      | -20  |      | dBc  |
| PAE           | Pout=18dBm | PAE    |      | 18   |      | %    |

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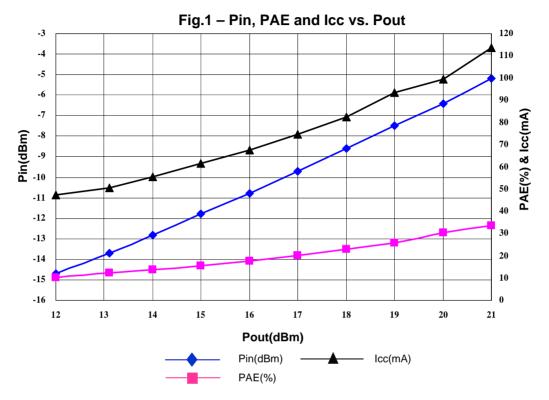
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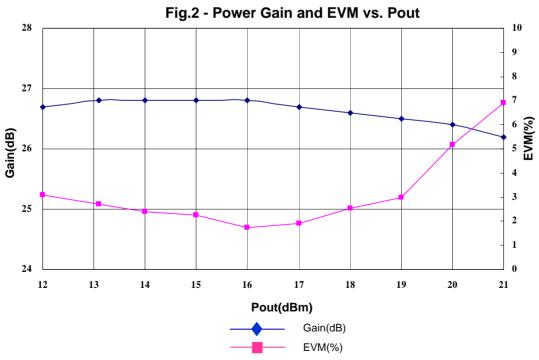


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## **Data Charts: WLAN Applications**





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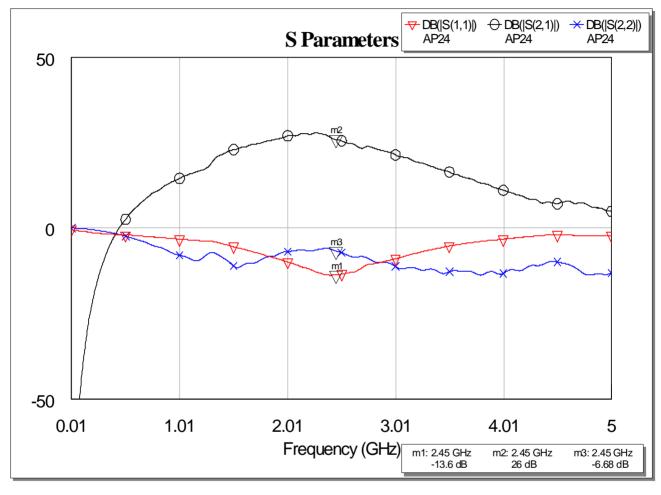
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### **Data Charts: WLAN Applications**

Fig.3 – S Parameters



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# **Data Charts: BT V1.1-1.2 Applications**

Fig.4

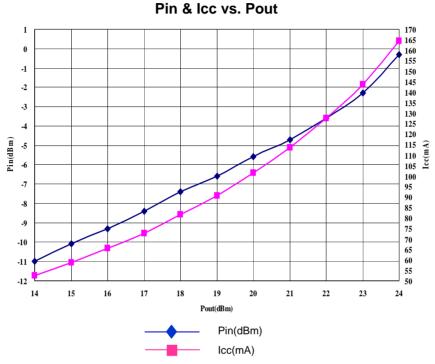
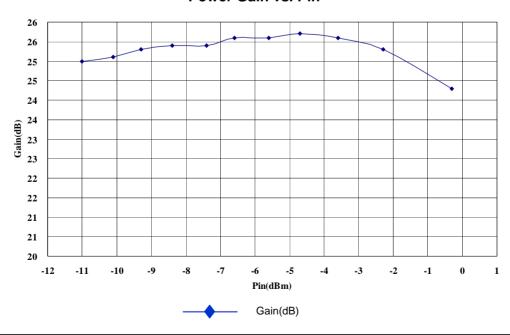


Fig.5

### Power Gain vs. Pin



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### Data Charts: BT V2.0(EDR) Applications

Fig.6

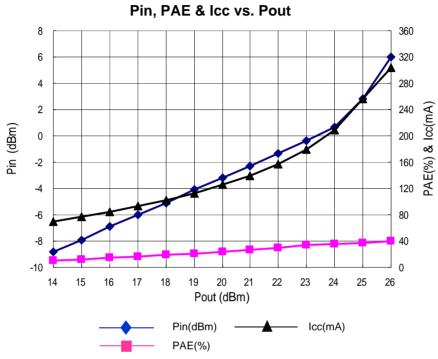
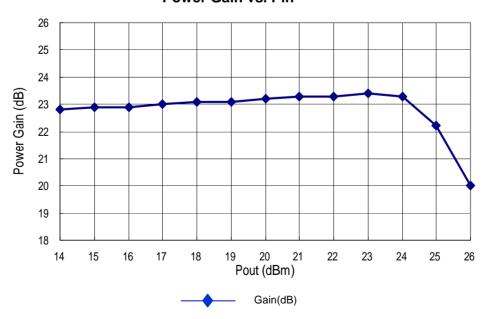


Fig.7

#### Power Gain vs. Pin



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### Data Charts: BT v.1.1-1.2 Applications

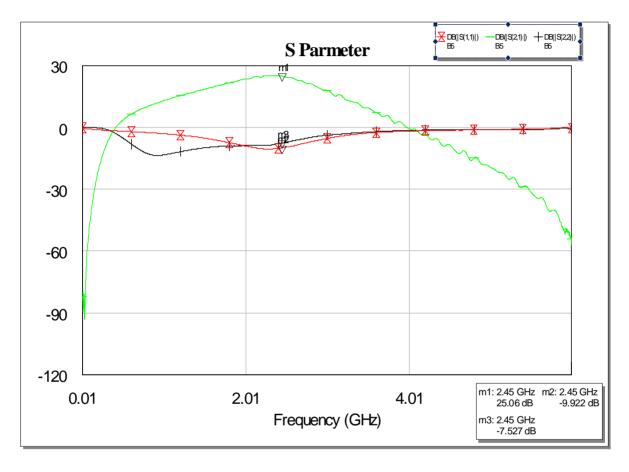


Fig.8

APTTT(

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### Data Charts: BT v.2.0(EDR) Applications

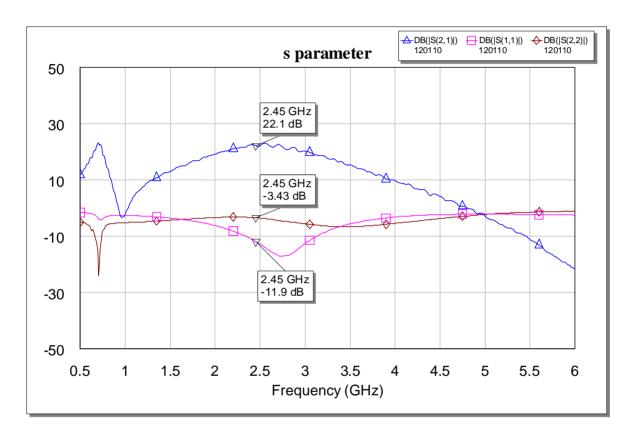


Fig.9

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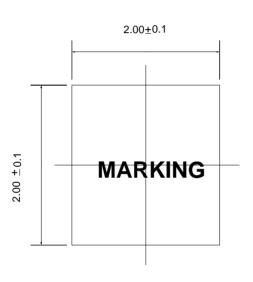
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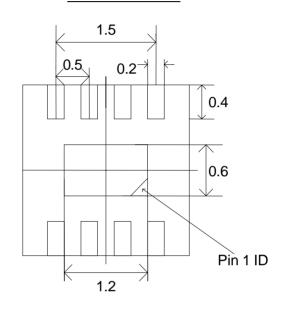
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# **Package Outline**

# **Top View**



### **Bottom View**



#### Unit: mm

## **Side View**



### Note:

- 1. Dimension and tolerance conform to ASME Y14.5M-1994.
- 2. Refer to JEDEC STD. MO-220 WEED-2 ISSUE B

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